

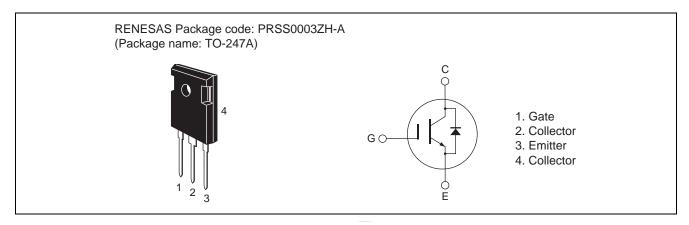
RJH60F6BDPQ-A0

600V - 45A - IGBT High Speed Power Switching R07DS0632EJ0100 Rev.1.00 Feb 17, 2012

Features

- Low collector to emitter saturation voltage $V_{CE(sat)}=1.35$ V typ. (at $I_C=45$ A, $V_{GE}=15$ V, Ta=25°C)
- Built in fast recovery diode in one package
- Trench gate and thin wafer technology
- High speed switching $t_f=74 \text{ ns typ. (at } I_C=30 \text{ A, } V_{CE}=400 \text{ V, } V_{GE}=15 \text{ V, } Rg=5 \Omega \text{, } Ta=25 ^{\circ}\text{C, inductive load)}$

Outline



Absolute Maximum Ratings

 $(Tc = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage		V _{CES}	600	V
Gate to emitter voltage		V _{GES}	±30	V
Collector current	Tc = 25 °C	Ic	85	A
	Tc = 100 °C	Ic	45	A
Collector peak current		ic(peak) Note1	170	A
Collector to emitter diode forward peak current		i _{DF} (peak) Note2	100	A
Collector dissipation		Pc	297.6	W
Junction to case thermal impedance (IGBT)		θј-с	0.42	°C/W
Junction to case thermal impedance (Diode)		θj-cd	1.1	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. Pulse width limited by safe operating area.

2. PW \leq 5 μ s, duty cycle \leq 1%

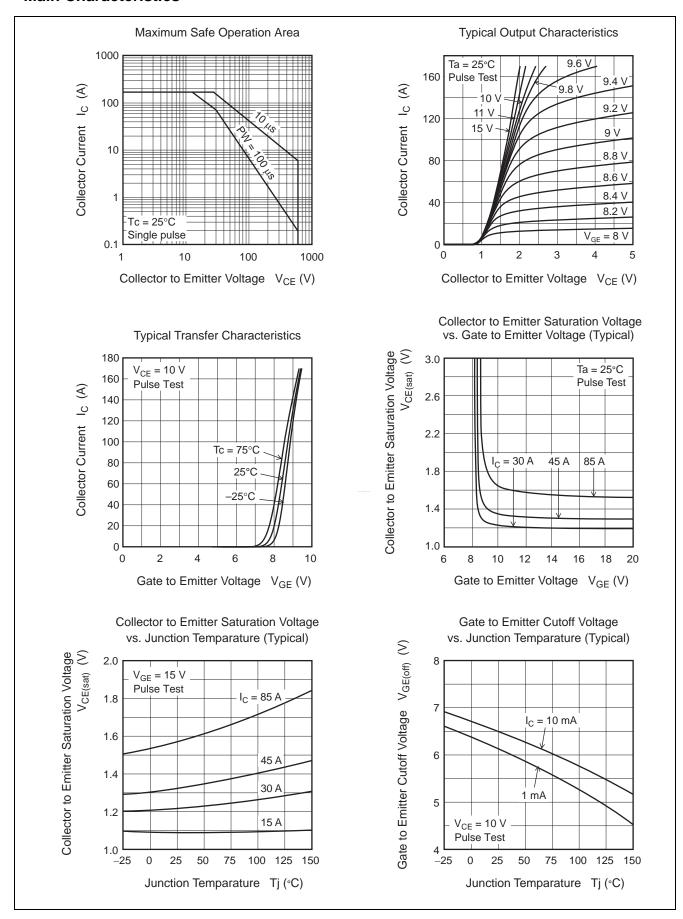
Electrical Characteristics

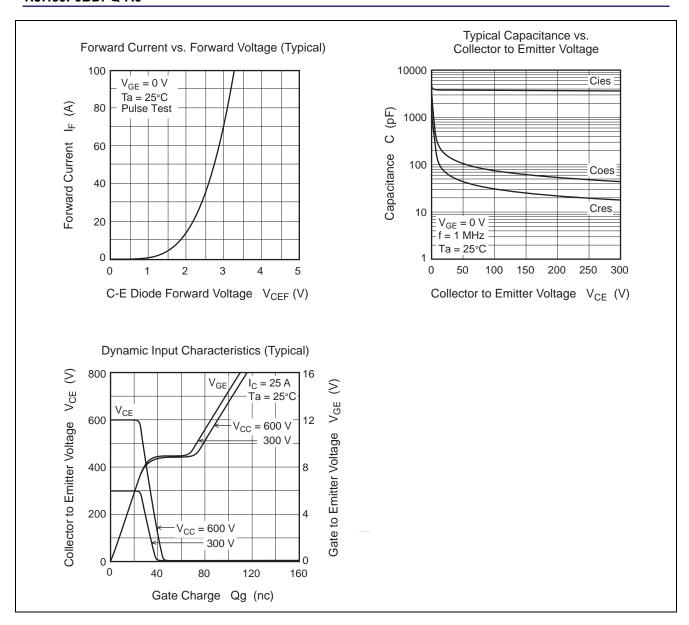
 $(Tj = 25^{\circ}C)$

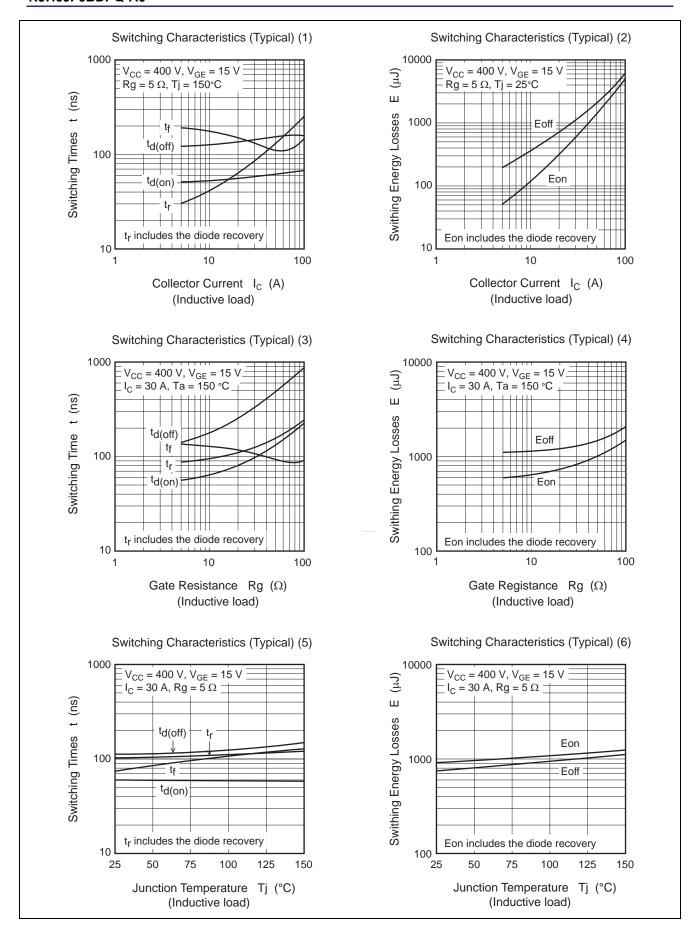
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current	I _{CES}	_	_	100	μΑ	$V_{CE} = 600 \text{ V}, V_{GE} = 0$
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$
Gate to emitter cutoff voltage	$V_{GE(off)}$	4	_	8	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	_	1.35	1.75	V	$I_C = 45 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
Input capacitance	Cies	_	3800	_	pF	V _{CE} = 25 V
Output capacitance	Coes	_	150	_	pF	$V_{GE} = 0 V$ f = 1 MHz
Reverse transfer capacitance	Cres	_	65	_	pF	
Switching time	t _{d(on)}	_	58	_	ns	$\begin{split} I_C &= 30 \text{ A}, \\ V_{CE} &= 400 \text{ V}, V_{GE} = 15 \text{ V} \\ Rg &= 5 \ \Omega^{Note3}, \end{split}$
	t _r	_	80	_	ns	
	t _{d(off)}	_	131	_	ns	
	t _f	_	74	_	ns	Inductive load
C-E diode forward voltage	V _{ECF}	_	2.5	3.0	V	I _F = 30 A Note3
C-E diode reverse recovery time	t _{rr}	_	25		ns	I _F = 30 A
						$di_F/dt = 100 A/\mu s$

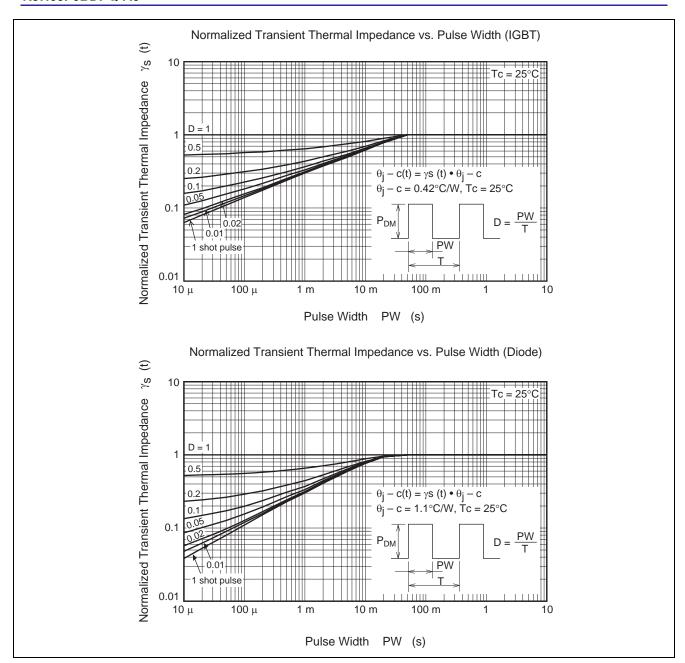
Notes: 3. Pulse test

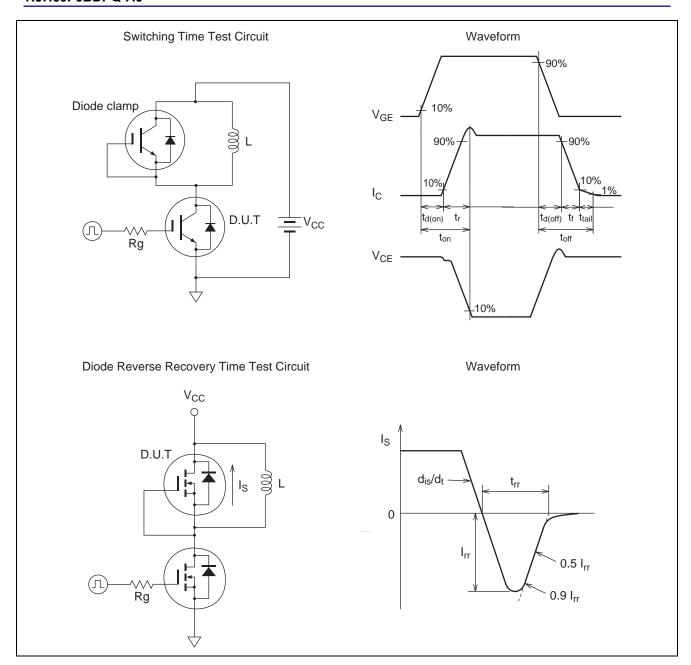
Main Characteristics



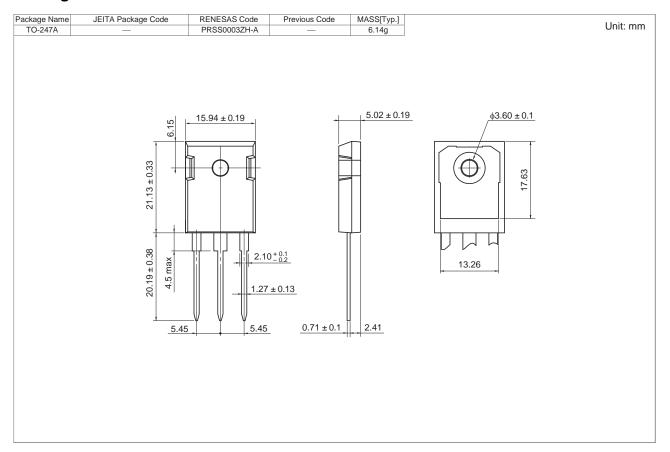








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60F6BDPQ-A0#T0	240 pcs	Box (Tube)

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